NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE30H10K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

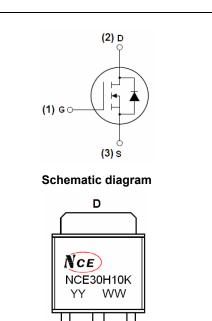
- V_{DS} =30V, I_D =100A $R_{DS(ON)}$ <5.5m Ω @ V_{GS} =10V (Typ:4m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



100% ΔVds TESTED!





TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE30H10K	NCE30H10K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	100	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	70	Α
Pulsed Drain Current	I _{DM}	400	Α
Maximum Power Dissipation	P _D	110	W
Single pulse avalanche energy (Note 5)	E _{AS}	350	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$



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NCE30H10K

Thermal Characteristic

Thermal Resistance, Junction-to-Case(Note 2)	R _{eJC}	1.36	°C/W	l
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Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	A 30		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	1	1.6	3	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	4.0	5.5	mΩ
Forward Transconductance	g FS	V _{DS} =10V,I _D =20A	50	-	-	S
Dynamic Characteristics (Note4)	·					
Input Capacitance	C _{lss}	\/ -35\/\/ -0\/		3300		PF
Output Capacitance	Coss	V_{DS} =25V, V_{GS} =0V, F=1.0MHz		1300		PF
Reverse Transfer Capacitance	C _{rss}	F=1.0IVID2		200		PF
Switching Characteristics (Note 4)	·					
Turn-on Delay Time	t _{d(on)}		-	11	-	nS
Turn-on Rise Time	t _r	V _{DD} =15V,I _D =60A	-	160	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =4.5 V , R_{GEN} =1.8 Ω	-	25	-	nS
Turn-Off Fall Time	t _f		-	60	-	nS
Total Gate Charge	Qg	\/ -45\/1 -204		100		nC
Gate-Source Charge	Q _{gs}	V_{DS} =15V, I_D =30A, V_{GS} =5V		25		nC
Gate-Drain Charge	Q_{gd}	V _{GS} -5V		45		nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current (Note 2)	Is			-	100	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 60A -		56	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs(Note3) - 110 -		nC		
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				
Diode Forward Current (Note 2) Reverse Recovery Time Reverse Recovery Charge	I _S t _{rr} Qrr	- TJ = 25°C, IF = 60A di/dt = 100A/µs(Note3)	-	- 56 110	100	

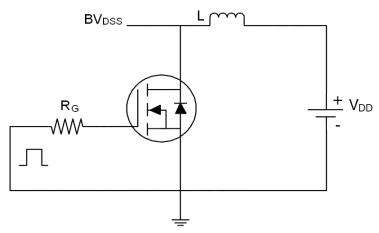
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V_{DD}=15V,V_G=10V,L=0.5mH,Rg=25 Ω

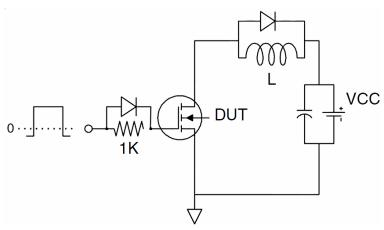
NCE30H10K

Test circuit

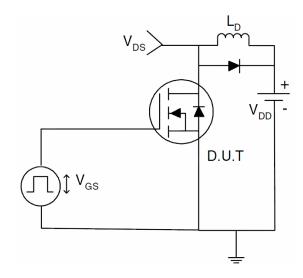
1) E_{AS} test Circuits



2) Gate charge test Circuit:



3) Switch Time Test Circuit:





Typical Electrical and Thermal Characteristics (Curves)

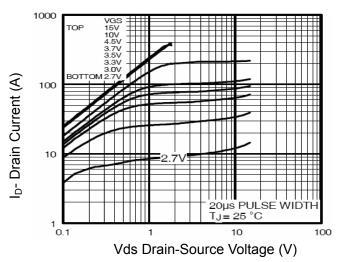


Figure 1 Output Characteristics

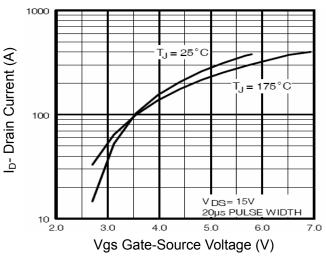


Figure 2 Transfer Characteristics

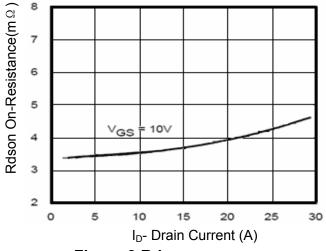


Figure 3 Rdson- Drain Current

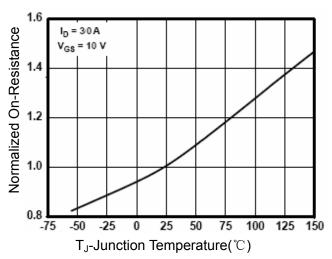


Figure 4 Rdson-JunctionTemperature

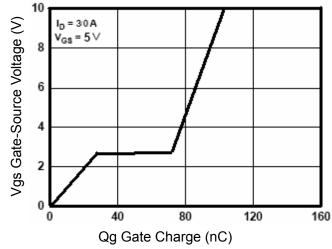


Figure 5 Gate Charge

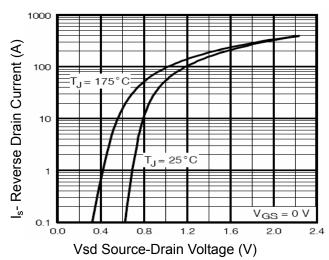


Figure 6 Source- Drain Diode Forward



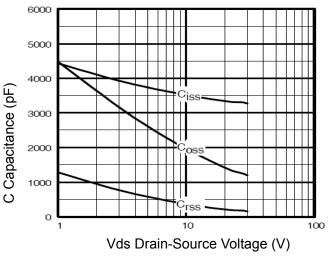


Figure 7 Capacitance vs Vds

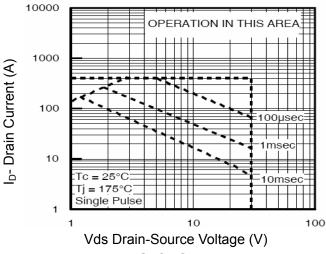


Figure 8 Safe Operation Area

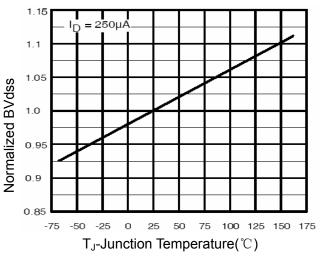


Figure 9 BV_{DSS} vs Junction Temperature

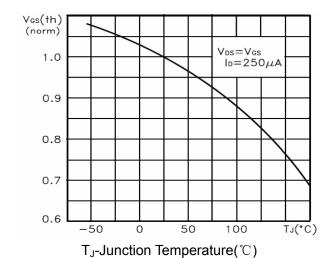


Figure 10 V_{GS(th)} vs Junction Temperature

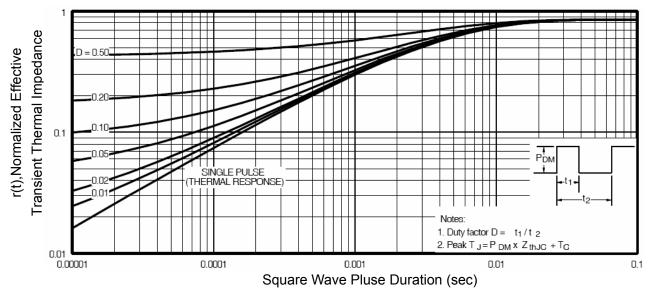
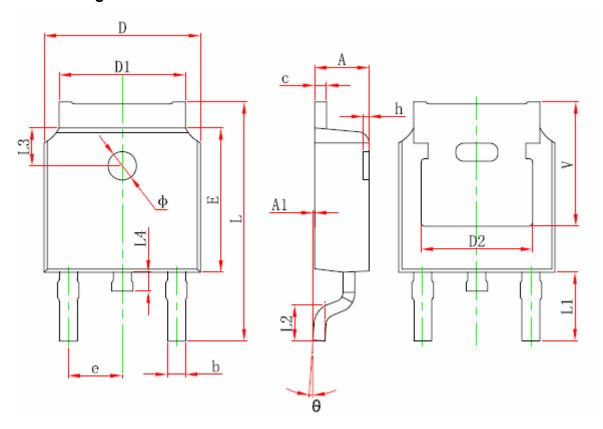


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252-2L Package Information



Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.830	REF.	0.190	90 REF.	
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	REF.	0.114 REF.		
L2	1.400	1.700	0.055	0.067	
L3	1.600	1.600 REF.		REF.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	REF.	0.211 REF.		



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